

## **INCHANGE SEMICONDUCTOR**

## **Isc N-Channel MOSFET Transistor**

## STD15NF10T4

### • FEATURES

- With To-252(DPAK) package
- Application oriented characterization
- Excellent switching performance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

Switching applications

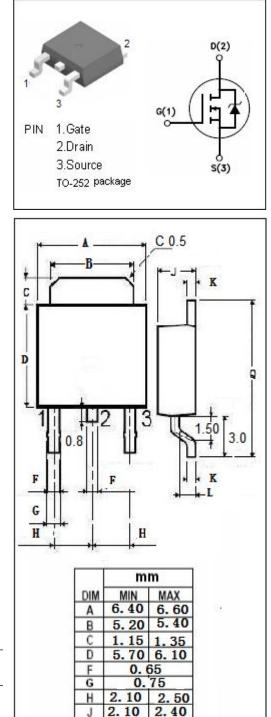
• ABSOLUTE MAXIMUM RATINGS(Ta=25 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	100	V				
V <sub>GSS</sub>	Gate-Source Voltage	±20	V				
ID	$\begin{array}{l} \mbox{Drain Current-Continuous} @T_{C} = 25 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $	23 16	A				
I <sub>DM</sub>	Drain Current-Single Pulsed	92	A				
PD	Total Dissipation @Tc=25°C	70	W				
T <sub>ch</sub>	Max. Operating Junction Temperature	175	°C				
T <sub>stg</sub>	Storage Temperature	-55~175	°C				

### • ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	2.14	°C <b>/W</b>	
Rth(ch-a)	h(ch-a) Channel-to-ambient thermal resistance		°C/W	

1



## isc website: www.iscsemi.cn

K

0

0.40

0.90

9.90

60

10



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### **ELECTRICAL CHARACTERISTICS**

#### $T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	100			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = ±20V; I <sub>D</sub> =0.25mA	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =12A		60	65	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0V; T <sub>J</sub> =25°C T <sub>J</sub> =125°C			1 10	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =20A, V <sub>GS</sub> = 0 V			1.5	v

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2